TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC7WH245FU, TC7WH245FK

**Dual Bus Transceiver** 

#### **FEATURES**

• High Speed :  $t_{pd} = 4.0 \text{ ns (typ.)}$ 

at  $V_{CC} = 5 \text{ V}$ ,  $C_L = 15 \text{pF}$ 

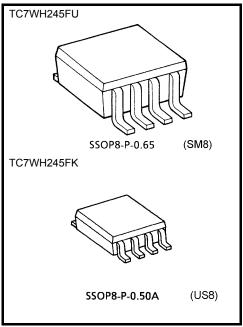
Low Power Dissipation : I<sub>CC</sub> = 2 μA (Max.) at Ta = 25°C
 High Noise Immunity : V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (Min.)

• Balanced Propagation Delays: t<sub>pLH</sub> ≈ t<sub>pHL</sub>

Wide Operating Voltage Range: V<sub>CC (opr)</sub> = 2 to 5.5 V
 Low Noise : V<sub>OLP</sub> = 0.8 V (Max.)

#### APPLICATION NOTES

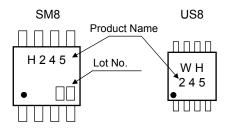
- 1) Do not apply a signal to any bus terminal when it is in the output mode. Damage may result.
- 2) All floating (high impedance) bus terminals must have their input levels fixed by means of pull up or pull down resistors.
- A parasitic diode is formed between the bus and Vcc terminals.
   Therefore bus terminal can not be used to interface 5V to 3V systems directly.



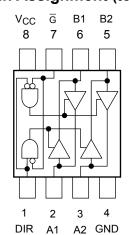
Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

#### Marking



#### Pin Assignment (top view)



## Absolute Maximum Ratings (Ta = 25°C)

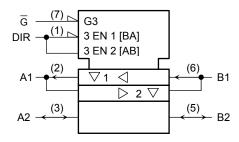
Characteristic	Symbol	Rating	Unit
Supply Voltage	V <sub>CC</sub>	−0.5 to 7	V
DC Input Voltage	V <sub>IN</sub>	–0.5 tp 7	V
DC Output Voltage	V <sub>OUT</sub>	-0.5 toV <sub>CC</sub> + 0.5	V
Input Diode Current	I <sub>IK</sub>	-20	mA
Output Diode Current	lok	±20 (Note 1)	mA
DC Output Current	lout	±25	mA
DC Vcc/Ground Current	ICC	±50	mA
Davies Discipation	Б	300(SM8)	\^/
Power Dissipation	P <sub>D</sub>	200(US8)	mW
Strage Temperature	T <sub>stg</sub>	-65 to 150	°C
LeadTemperature(10s)	TL	260	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>

## **IEC Logic Symbol**



#### **Truth Table**

Input		Fund	Output	
G	DIR	A BUS B BUS		Output
L	L	OUTPUT INPUT		A = B
L	Н	INPUT OUTPUT		B = A
Н	Х	High im	Z	

X: Don't care

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Z: High impedance

#### **Operating Ranges**

Characteristic	Symbol	Rating	Unit	
Supply Voltage	V <sub>CC</sub>	2 to 5.5	V	
Input Voltage	V <sub>IN</sub>	0 to 5.5	V	
Output Voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V	
Operating Temperature	T <sub>opr</sub>	-40 to 85	°C	
Input Rise and Fall Time	d <sub>t</sub> /d <sub>v</sub>	0 to 100 ( $V_{CC} = 3.3 \pm 0.3 \text{ V}$ )	ns/V	
iliput Nise anu i ali Tilile	u <sub>t</sub> /u <sub>V</sub>	0 to 20 ( $V_{CC} = 5.0 \pm 0.5 \text{ V}$ )		



## **Electrical Characteristics**

#### **DC Characteristics**

Characteristic Symbol Test Condition				Га = 25°0		Ta = -40	) to 85°C	Unit		
		onaition	V <sub>CC</sub> (V)	Min.	Тур.	Max.	Min.	Max.	Uniit	
High-Level					1.5	_	_	1.5	_	
Input Voltage	V <sub>IH</sub>	_		3.0 to 5.5	V <sub>CC</sub> × 0.7	_	_	V <sub>CC</sub> × 0.7	_	V
Low-Level				2.0		_	0.5	_	0.5	V
Input Voltage	V <sub>IL</sub>		_			_	V <sub>CC</sub> × 0.3	_	V <sub>CC</sub> × 0.3	
				2.0	1.9	2.0	_	1.9	_	
High-Level Output Voltage	Voн	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -50 \mu A$	3.0	2.9	3.0	_	2.9	_	
				4.5	4.4	4.5	_	4.4	_	
			I <sub>OH</sub> = -4 mA	3.0	2.58	_	_	2.48	_	
			$I_{OH} = -8 \text{ mA}$	4.5	3.94	_	_	3.80	_	V
	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0		0.0	0.1	_	0.1	V
				3.0		0.0	0.1	_	0.1	
Low-Level Output Voltage				4.5		0.0	0.1	_	0.1	
- 2.η a			$I_{OL} = 4 \text{ mA}$	3.0		_	0.36	_	0.44	
			$I_{OL} = 8 \text{ mA}$	4.5		_	0.36	_	0.44	
3-State Output Off-State Current	loz	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	_	±0.25	_	±2.50	μΑ
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5			±0.1		±1.0	μΑ
Quiescent Spply Current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	2.0	_	20.0	μА

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## AC Characteristics (Input: $t_r = t_f = 3$ ns)

Characteristic	Symbol Test Condition <sub>T</sub>				Ta = 25°C			Ta =-40 to 85°C		Unit
Characteristic Symbo		Test Condition V <sub>CC</sub>		C <sub>L</sub> (pF)	Min.	Тур.	Max.	Min.	Max.	Unit
			3.3 ± 0.3	15	_	5.8	8.4	1.0	10.0	
Propagation Delay	t <sub>pLH</sub>		3.3 ± 0.3	50	_	8.3	11.9	1.0	13.5	ns
Time	t <sub>pHL</sub>	_	5.0 ± 0.5	15		4.0	5.5	1.0	6.5	113
			5.0 ± 0.5	50		5.5	7.5	1.0	8.5	
3-State Output Enable Time		R <sub>L</sub> = 1 kΩ	3.3 ± 0.3	15		8.5	13.2	1.0	15.5	
	$t_{pZL}$ $t_{pZH}$ $R_L = 1 k\Omega$			50		11.0	16.7	1.0	19.0	ns
			5.0 ± 0.5	15		5.8	8.5	1.0	10.0	113
			3.0 ± 0.5	50		7.3	10.6	1.0	12.0	
3-State Output	t <sub>pLZ</sub>	R <sub>L</sub> = 1 kΩ	$3.3 \pm 0.3$	50		11.5	15.8	1.0	18.0	ns
Disable Time	Disable Time t <sub>pHZ</sub>	N 1 K22	$5.0\pm0.5$	50		7.0	9.7	1.0	11.0	115
Output to Output	t <sub>osLH</sub>	(Note 2)	$3.3 \pm 0.3$	50		_	1.5	_	1.5	ns
Skew	t <sub>osHL</sub>	(Note 2)	$5.0\pm0.5$	50		_	1.0	_	1.0	115
Input Capacitance	C <sub>IN</sub>	DIR, G				4	10	_	10	pF
Bus Input Capacitance	C <sub>I/O</sub>	An, Bn			_	8	_	_	_	pF
Power Dissipation Capacitance	C <sub>PD</sub>			(Note 3)	_	21	_	_	_	pF

Note 2: Parameter guranteed by design.

 $t_{\mathsf{OSLH}} = |t_{\mathsf{PLHm}} - t_{\mathsf{PLHn}}|, \, t_{\mathsf{OSHL}} = |t_{\mathsf{PHLm}} - t_{\mathsf{PHLn}}|$ 

Note 3: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calucurated from the operating current consumption without load.

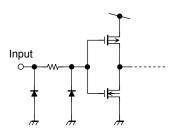
Average iperating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per bit)}$ 

## Noise Characteristics (Ta = $25^{\circ}$ C, Input: $t_r = t_f = 3$ ns)

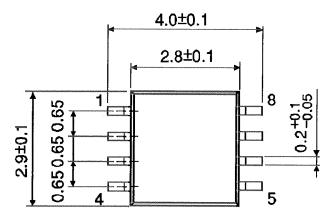
Characteritic	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet Output Maximum Dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.5	0.8	V
Quiet Output Minimum Dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.5	-0.8	V
Minimum High Level Dynamic Input Voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0		3.5	V
Maximum Low Level Dynamic Input Voltage	$V_{ILD}$	C <sub>L</sub> = 50 pF	5.0		1.5	V

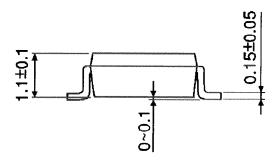
## **Input Equivalent Circuit**



# **Package Dimensions**

SSOP8-P-0.65 Unit: mm



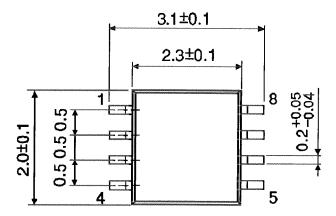


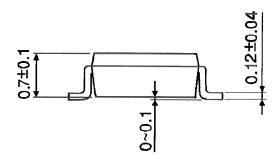
5

Weight: 0.02 g (Typ.)

# **Package Dimensions**

SSOP8-P-0.50A Unit: mm





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Weight: 0.01 g (Typ.)

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